An 11,424 gate-count dynamic optically reconfigurable gate array with a photodiode memory architecture

Daisaku Seto and Minoru Watanabe Department of Electrical and Electronic Engineering Shizuoka University



Gate array structure



An ORGA takes Island-Style gate array. The basic structure is same as that of current FPGAs. However, each programming element of the gate array is connected to a photodiode (independent). Thereby, all state of the gate array can be programmed in perfectly parallel.

Dynamic optical reconfiguration circuit



Dynamic optical reconfiguration circuit



1bit-Dynamic Type Reconfiguration Circuit

$$36 \ [\mu m^2]$$

DORGA-VLSI Specifications

SM L SM L	B SN B SN	1 LB 1 LB	SM SM	••	•	LB LB	SM SM
SM L SM	BSN	1 LB	SM			LB	SM
SM		•					
•		•	•				
•			•	,			
•				•		•	
SM SM	•	•	•	•		LB	SM
Logic Block (LB) × 336 •Switching Matrix (SM) × 360							
∙Switchin •I/O bits	ng Matrix	(SM)× ×	360 32				
-Switchin ∙I/O bits	ng Matrix Pla		³⁶⁰ 32 me1	nt			
• Switchin • I/O bits	ng Matrix Pl:		³⁶⁰ 32 me1	nt			
- Switchin • I/O bits	ng Matrix P1:			nt			
- Switchin · I/O bits	ng Matrix P1:		³⁶⁰ 32 mei	nt			
- Switchin - I/O bits	ng Matrix P1:			nt			
- Switchin - I/O bits	ng Matrix P1:			nt			
- Switchin - I/O bits	ng Matrix P1:			nt			
- Switchin +I/O bits	ng Matrix P1:			nt			

Chip Photograph

Specification of a DORGA-VLSI					
Technology	0.35 μm double-poly				
	triple-metal CMOS process				
Chip size	9.8 × 9.8 [mm]				
Supply Voltage	Core 3.3V, I/O 3.3V				
Photodiode size	$9.5 \times 8.8 \ [\mu m]$				
Distance between					
Photodiodes	h.=34.5, v.= 33.0 $[\mu m]$				
Number of					
Photodiodes	37,856				
Number of					
Logic Blocks	336				
Number of					
Switching Matrices	360				
Number of Wires					
in a Routing Channel	8				
Number of					
I/O blocks	8 (32 bit)				
Gate Count	11,424				

Experimental results





Holographic memory

Context pattern

AND circuit implementation

Optical system

Laser:632.8nm 20mW He-Ne laserHolographic memoryLiquid crystal –spatial light modulatorRetention time45 s.Photodiode response time12.7pJ/Laser power